NSN 5962-01-051-6539

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-051-6539

Bodv	ı I er	nath:

Between 1.065 inches and 1.095 inches

Body Width:

Between 0.380 inches and 0.396 inches

Body Height:

Between 0.090 inches and 0.130 inches

Maximum Power Dissipation Rating:

276.5 milliwatts

Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Monolithic and hermetically sealed and positive outputs and 3-state output and w/enable and w/disable and low power and w/decoded output and bipolar and w/buffered output and w/storage

Inclosure Material:

Ceramic and metal

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

16 input

Terminal Surface Treatment:

Gold

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

35.00 nanoseconds propagation delay time, low to high level output and 45.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Precious Material And Location:

Terminal surfaces gold

Precious Material:

Gold

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

22 printed circuit

Shelf Life:

N/a

NSN 5962-01-051-6539

Memory Microcircuit - Page 2 of 2



Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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